



# 30V N-Channel NexFET™ Power MOSFET

## **FEATURES**

- Qualified for Automotive Applications
- Optimized for 5V Gate Drive
- Ultra Low Q<sub>q</sub> and Q<sub>qd</sub>
- Low Thermal Resistance
- Pb Free
- RoHS Compliant
- Halogen Free
- SON 2-mm × 2-mm Plastic Package

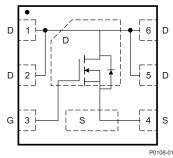
## **APPLICATIONS**

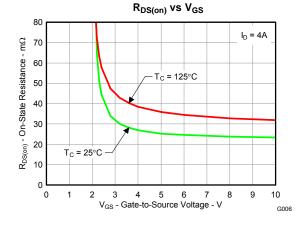
- DC-DC Converters
- Battery and Load Management Applications

## DESCRIPTION

The NexFET power MOSFET has been designed to minimize losses in power conversion applications and optimized for 5V gate drive applications. The 2-mm × 2-mm SON offers excellent thermal performance for the size of the package.







## PRODUCT SUMMARY

V <sub>DS</sub>	Drain to Source Voltage 30				
$Q_g$	Gate Charge Total (4.5V)	2.1	nC		
$Q_{gd}$	Gate Charge Gate to Drain	0.4	nC		
		$V_{GS} = 3V$	31	mΩ	
R <sub>DS(on)</sub>	Drain to Source On Resistance	$V_{GS} = 4.5V$	26	mΩ	
		V <sub>GS</sub> = 8V 24		mΩ	
$V_{GS(th)}$	Threshold Voltage	1.3	V		

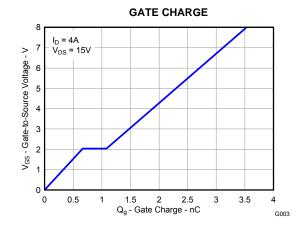
#### ORDERING INFORMATION

Device	Package	Media	Qty	Ship
CSD17313Q2Q1	SON 2-mm × 2-mm Plastic Package	13-Inch Reel	3000	Tape and Reel

#### **ABSOLUTE MAXIMUM RATINGS**

$T_A = 25^\circ$	°C unless otherwise stated	VALUE	UNIT
$V_{DS}$	Drain to Source Voltage	30	V
$V_{GS}$	Gate to Source Voltage	+10 / -8	>
	Continuous Drain Current, T <sub>C</sub> = 25°C	5	Α
ID.	Continuous Drain Current <sup>(1)</sup>		Α
$I_{DM}$	Pulsed Drain Current, T <sub>A</sub> = 25°C <sup>(2)</sup>	20	Α
$P_D$	Power Dissipation	2.3	W
$T_J$ , $T_{STG}$	Operating Junction and Storage Temperature Range	-55 to 150	°C
E <sub>AS</sub>	Avalanche Energy, Single Pulse, $I_D = 19A$ , $L = 0.1 mH$ , $R_G = 25\Omega$	18	mJ

- (1) Package Limited
- (2) Pulse duration ≤300µs, duty cycle ≤2%





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## **ELECTRICAL CHARACTERISTICS**

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Ch	naracteristics					
BV <sub>DSS</sub>	Drain to Source Voltage	$V_{GS} = 0V, I_{D} = 250\mu A$	30			V
I <sub>DSS</sub>	Drain to Source Leakage	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 24V			1	μΑ
I <sub>GSS</sub>	Gate to Source Leakage	$V_{DS} = 0V, V_{GS} = +10 / -8V$			100	nA
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$	0.9	1.3	1.8	V
		$V_{GS} = 3V$ , $I_D = 4A$		31	42	mΩ
R <sub>DS(on)</sub>	Drain to Source On Resistance	$V_{GS} = 4.5V, I_D = 4A$		26	32	mΩ
		$V_{GS} = 8V$ , $I_D = 4A$		24	30	mΩ
9 <sub>fs</sub>	Transconductance	$V_{DS} = 15V, I_{D} = 4A$		16		S
Dynamic	Characteristics				•	
C <sub>iss</sub>	Input Capacitance			260	340	pF
C <sub>oss</sub>	Output Capacitance	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 15V, f = 1MHz		140	180	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	1 - 11/11/2		13	17	pF
$R_{G}$	Series Gate Resistance			1.3	2.6	Ω
Qg	Gate Charge Total (4.5V)			2.1	2.7	nC
$Q_{gd}$	Gate Charge – Gate to Drain	$V_{DS} = 15V$ ,		0.4		nC
Q <sub>gs</sub>	Gate Charge Gate to Source	$I_D = 4A$		0.7		nC
Q <sub>g(th)</sub>	Gate Charge at Vth			0.3		nC
Q <sub>oss</sub>	Output Charge	$V_{DS} = 13.5V, V_{GS} = 0V$		3.8		nC
t <sub>d(on)</sub>	Turn On Delay Time			2.8		ns
t <sub>r</sub>	Rise Time	$V_{DS} = 15V, V_{GS} = 4.5V,$		3.9		ns
t <sub>d(off)</sub>	Turn Off Delay Time	$I_D = 4A, R_G = 2\Omega$		4.2		ns
t <sub>f</sub>	Fall Time			1.3		ns
Diode Ch	naracteristics					
V <sub>SD</sub>	Diode Forward Voltage	$I_{SD} = 4A$ , $V_{GS} = 0V$		0.85	1	V
$Q_{rr}$	Reverse Recovery Charge	V <sub>DD</sub> = 13.5V, I <sub>F</sub> = 4A,		6.4		nC
t <sub>rr</sub>	Reverse Recovery Time	di/dt = 300A/µs		12.9		ns

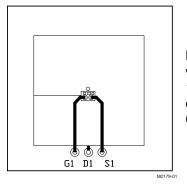
## THERMAL CHARACTERISTICS

(T<sub>A</sub> = 25°C unless otherwise stated)

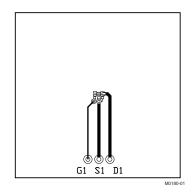
	PARAMETER	MIN	TYP	MAX	TINU
$R_{\theta JC}$	Thermal Resistance Junction to Case <sup>(1)</sup>			7.4	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient <sup>(1)(2)</sup>			67	°C/W

 $R_{\theta JC}$  is determined with the device mounted on a 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inch x 1.5-inch (3.81-cm x 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB.  $R_{\theta JC}$  is specified by design, whereas  $R_{\theta JA}$  is determined by the user's board design. Device mounted on FR4 material with 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu.





Max  $R_{\theta JA} = 67^{\circ}\text{C/W}$  when mounted on 1 inch² (6.45 cm²) of 2-oz. (0.071-mm thick) Cu.



Max  $R_{\theta JA} = 228^{\circ} C/W$  when mounted on a minimum pad area of 2-oz. (0.071-mm thick) Cu.

## TYPICAL MOSFET CHARACTERISTICS

(T<sub>A</sub> = 25°C unless otherwise stated)

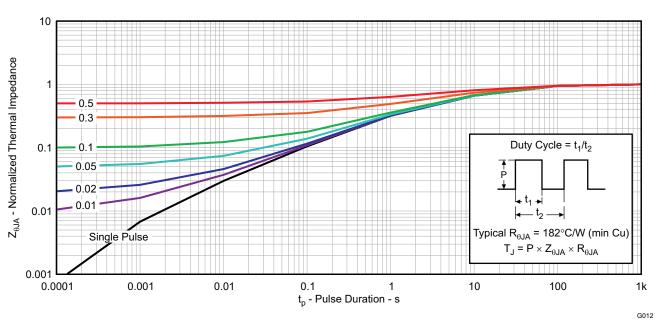


Figure 1. Transient Thermal Impedance



## TYPICAL MOSFET CHARACTERISTICS (continued)

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 

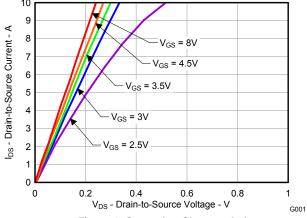


Figure 2. Saturation Characteristics

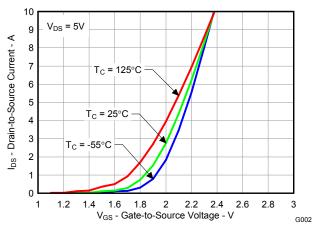


Figure 3. Transfer Characteristics

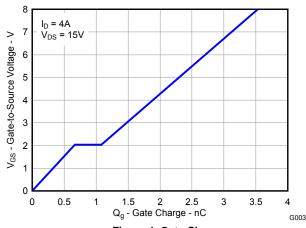


Figure 4. Gate Charge

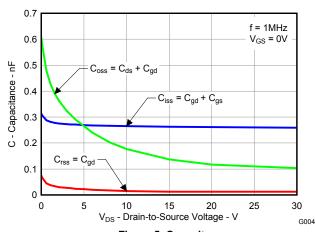


Figure 5. Capacitance

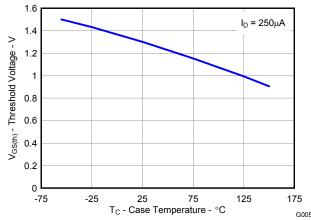


Figure 6. Threshold Voltage vs. Temperature

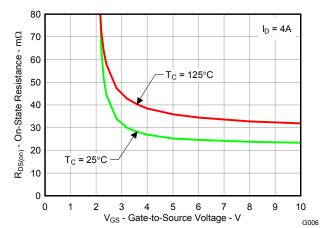


Figure 7. On-State Resistance vs. Gate-to-Source Voltage



# **TYPICAL MOSFET CHARACTERISTICS (continued)**

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 

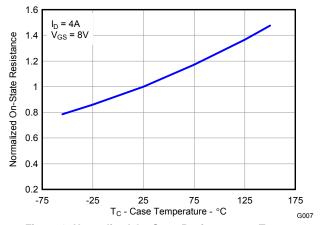


Figure 8. Normalized On-State Resistance vs. Temperature

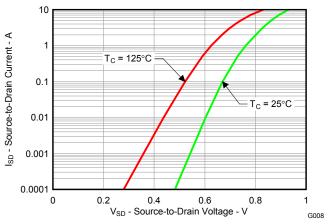


Figure 9. Typical Diode Forward Voltage

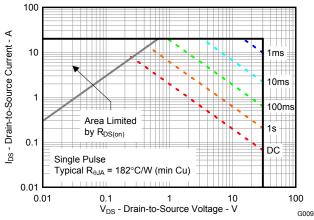


Figure 10. Maximum Safe Operating Area

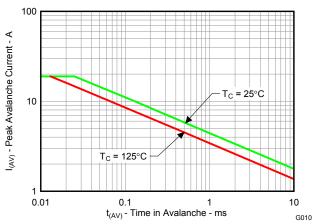


Figure 11. Single Pulse Unclamped Inductive Switching

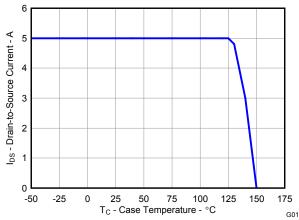
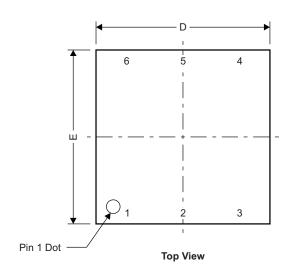


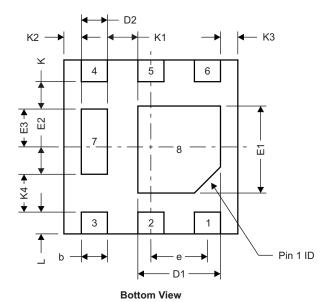
Figure 12. Maximum Drain Current vs. Temperature

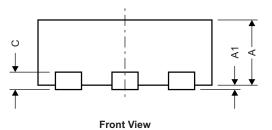


## **MECHANICAL DATA**

# **Q2 Package Dimensions**







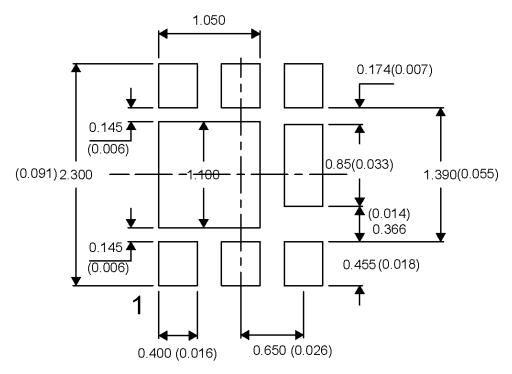
Pinout					
Source	4, 7				
Gate	3				
Drain	1, 2, 5, 6, 8				

M0175-02

DIM		MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.700	0.750	0.800	0.028	0.030	0.032	
A1	0.000		0.050	0.000		0.002	
b	0.250	0.300	0.350	0.010	0.012	0.014	
С		0.203 TYP			0.008 TYP		
D		2.000 TYP			0.080 TYP		
D1	0.900	0.950	1.000	0.036	0.038	0.040	
D2	0.300 TYP 0.012 TYP						
E		2.000 TYP		0.080 TYP			
E1	0.900	1.000 1.100		0.036	0.040	0.044	
E2		0.280 TYP			0.0112 TYP		
E3		0.470 TYP			0.0188 TYP		
е		0.650 BSC			0.026 TYP		
K		0.280 TYP			0.0112 TYP		
K1		0.350 TYP			0.014 TYP		
K2	0.200 TYP 0.008 TYP						
K3		0.200 TYP			0.008 TYP		
K4		0.470 TYP			0.0188 TYP		
L	0.200	0.25	0.300	0.008	0.010	0.012	

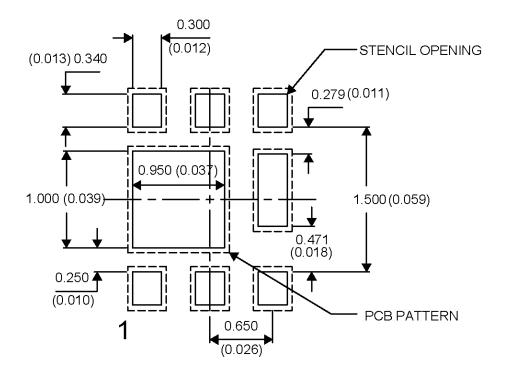


## **Recommended PCB Pattern**



For recommended circuit layout for PCB designs, see application note SLPA005 – *Reducing Ringing through PCB Layout Techniques*.

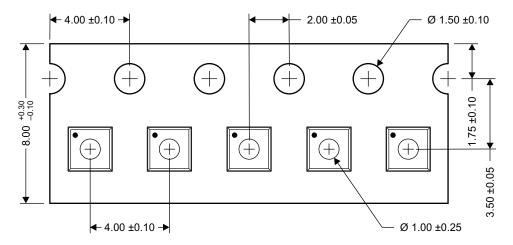
## **Recommended Stencil Pattern**

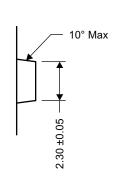


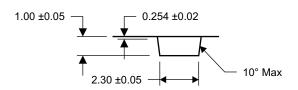
Note: All dimensions are in mm, unless otherwise specified.



## **Q2 Tape and Reel Information**







M0168-01

Notes: 1. Measured from centerline of sprocket hole to centerline of pocket

- 2. Cumulative tolerance of 10 sprocket holes is ±0.20
- 3. Other material available
- 4. Typical SR of form tape Max 108 OHM/SQ
- 5. All dimensions are in mm, unless otherwise specified.

## **REVISION HISTORY**

# Changes from Original (October 2012) to Revision A Page • Changed the device number From: CSD17313Q2-Q1 To: CSD17313Q2Q1 1 Changes from Revision A (November 2012) to Revision B Page • Changed the Recommended PCB Pattern 7 • Added the Recommended Stencil Pattern 7





8-Jan-2013

#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	_	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Samples
	(1)		Drawing			(2)		(3)	(Requires Login)
CSD17313Q2Q1	ACTIVE	SON	DQK	6	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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